

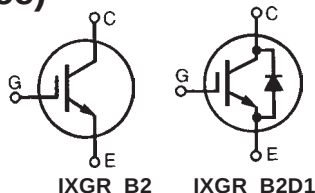
# HiPerFAST™ IGBT ISOPLUS247™

## B2-Class High Speed IGBTs (Electrically Isolated Back Surface)

Preliminary Data Sheet

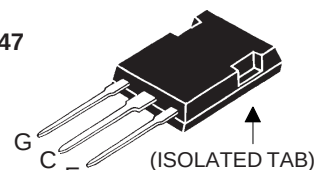
IXGR 50N60B2  
IXGR 50N60B2D1

$V_{CES} = 600 \text{ V}$   
 $I_{C25} = 68 \text{ A}$   
 $V_{CE(sat)} = 2.2 \text{ V}$   
 $t_{fi(typ)} = 65 \text{ ns}$



| Symbol                                                                          | Test Conditions                                                                                                                    | Maximum Ratings |                  |
|---------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------|-----------------|------------------|
| $V_{CES}$                                                                       | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$                                                                                    | 600             | V                |
| $V_{CGR}$                                                                       | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$ ; $R_{GE} = 1 \text{ M}\Omega$                                                     | 600             | V                |
| $V_{GES}$                                                                       | Continuous                                                                                                                         | $\pm 20$        | V                |
| $V_{GEM}$                                                                       | Transient                                                                                                                          | $\pm 30$        | V                |
| $I_{C25}$                                                                       | $T_C = 25^\circ\text{C}$ (limited by leads)                                                                                        | 68              | A                |
| $I_{C110}$                                                                      | $T_C = 110^\circ\text{C}$                                                                                                          | 36              | A                |
| $I_{F110}$                                                                      | $T_C = 110^\circ\text{C}$ (50N60B2D1 Diode)                                                                                        | 39              | A                |
| $I_{CM}$                                                                        | $T_C = 25^\circ\text{C}$ , 1 ms                                                                                                    | 300             | A                |
| <b>SSOA</b><br><b>(RBSOA)</b>                                                   | $V_{GE} = 15 \text{ V}$ , $T_{VJ} = 125^\circ\text{C}$ , $R_G = 10 \Omega$<br>Clamped inductive load @ $V_{CE} \leq 600 \text{ V}$ | $I_{CM} = 100$  | A                |
| $P_C$                                                                           | $T_C = 25^\circ\text{C}$                                                                                                           | 200             | W                |
| $T_J$                                                                           |                                                                                                                                    | -55 ... +150    | $^\circ\text{C}$ |
| $T_{JM}$                                                                        |                                                                                                                                    | 150             | $^\circ\text{C}$ |
| $T_{stg}$                                                                       |                                                                                                                                    | -55 ... +150    | $^\circ\text{C}$ |
| $V_{ISOL}$                                                                      | 50/60 Hz RMS, $t = 1 \text{ m}$                                                                                                    | 2500            | V                |
| <b>Weight</b>                                                                   | 5                                                                                                                                  | g               |                  |
| Maximum lead temperature for soldering<br>1.6 mm (0.062 in.) from case for 10 s |                                                                                                                                    | 300             | $^\circ\text{C}$ |

ISOPLUS247  
(IXGR)



G = Gate  
E = Emitter  
C = Collector

### Features

- DCB Isolated mounting tab
- Meets TO-247AD package Outline
- High current handling capability
- Latest generation HDMOS™ process
- MOS Gate turn-on  
- drive simplicity

### Applications

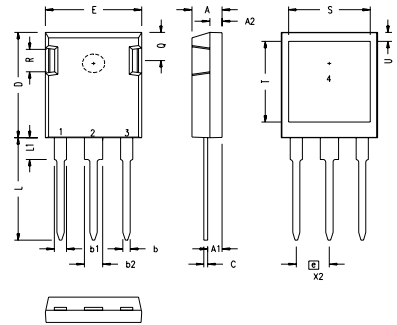
- Uninterruptible power supplies (UPS)
- Switched-mode and resonant-mode power supplies
- AC motor speed control
- DC servo and robot drives
- DC choppers

### Advantages

- Easy assembly
- High power density
- Very fast switching speeds for high frequency applications

| Symbol        | Test Conditions                                          | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |            |           |
|---------------|----------------------------------------------------------|-----------------------------------------------------------------------------------|------------|-----------|
|               |                                                          | Min.                                                                              | Typ.       | Max.      |
| $V_{GE(th)}$  | $I_C = 250 \mu\text{A}$ , $V_{CE} = V_{GE}$              | 3.0                                                                               |            | 5.0       |
| $I_{CES}$     | $V_{CE} = V_{CES}$<br>$V_{GE} = 0 \text{ V}$             | 50N60B2<br>50N60B2D1                                                              |            | 50<br>650 |
| $I_{GES}$     | $V_{CE} = 0 \text{ V}$ , $V_{GE} = \pm 20 \text{ V}$     |                                                                                   |            | $\pm 100$ |
| $V_{CE(sat)}$ | $I_C = 40 \text{ A}$ , $V_{GE} = 15 \text{ V}$<br>Note 1 |                                                                                   | 1.8<br>1.7 | 2.2<br>V  |

| Symbol        | Test Conditions                                                                                                                                      | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |          |
|---------------|------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------|------|----------|
|               |                                                                                                                                                      | Min.                                                                              | Typ. | Max.     |
| $g_{fs}$      | $I_C = 40\text{ A}$ ; $V_{CE} = 10\text{ V}$ ,<br>Note 1                                                                                             | 40                                                                                | 55   | S        |
| $C_{ies}$     | $V_{CE} = 25\text{ V}$ , $V_{GE} = 0\text{ V}$ , $f = 1\text{ MHz}$                                                                                  | 50N60B2<br>50N60B2D1                                                              | 3500 | pF       |
| $C_{oes}$     |                                                                                                                                                      |                                                                                   | 240  | pF       |
| $C_{res}$     |                                                                                                                                                      |                                                                                   | 280  | pF       |
|               |                                                                                                                                                      |                                                                                   | 50   | pF       |
| $Q_g$         | $I_C = 40\text{ A}$ , $V_{GE} = 15\text{ V}$ , $V_{CE} = 0.5 V_{CES}$                                                                                |                                                                                   | 140  | nC       |
| $Q_{ge}$      |                                                                                                                                                      |                                                                                   | 23   | nC       |
| $Q_{gc}$      |                                                                                                                                                      |                                                                                   | 44   | nC       |
| $t_{d(on)}$   | Inductive load, $T_J = 25^\circ\text{C}$<br>$I_C = 40\text{ A}$ , $V_{GE} = 15\text{ V}$<br>$V_{CE} = 480\text{ V}$ , $R_G = R_{off} = 5.0\ \Omega$  |                                                                                   | 18   | ns       |
| $t_{ri}$      |                                                                                                                                                      |                                                                                   | 25   | ns       |
| $t_{d(off)}$  |                                                                                                                                                      |                                                                                   | 190  | ns       |
| $t_{fi}$      |                                                                                                                                                      |                                                                                   | 65   | ns       |
| $E_{off}$     |                                                                                                                                                      |                                                                                   | 0.55 | 0.85 mJ  |
| $t_{d(on)}$   | Inductive load, $T_J = 125^\circ\text{C}$<br>$I_C = 40\text{ A}$ , $V_{GE} = 15\text{ V}$<br>$V_{CE} = 480\text{ V}$ , $R_G = R_{off} = 5.0\ \Omega$ |                                                                                   | 18   | ns       |
| $t_{ri}$      |                                                                                                                                                      |                                                                                   | 25   | ns       |
| $E_{on}$      |                                                                                                                                                      |                                                                                   | 0.9  | mJ       |
| $t_{d(off)}$  |                                                                                                                                                      |                                                                                   | 290  | ns       |
| $t_{fi}$      |                                                                                                                                                      |                                                                                   | 140  | ns       |
| $E_{off}$     |                                                                                                                                                      |                                                                                   | 1.55 | mJ       |
| $R_{thJ-DCB}$ | (Note 2)                                                                                                                                             | 0.31                                                                              | 0.62 | K/W      |
| $R_{thJC}$    | (Note 3)                                                                                                                                             |                                                                                   |      | K/W      |
| $R_{thCS}$    |                                                                                                                                                      |                                                                                   |      | 0.15 K/W |

**ISOPLUS 247 Outline**


| SYM | INCHES   |      | MILLIMETERS |       |
|-----|----------|------|-------------|-------|
|     | MIN      | MAX  | MIN         | MAX   |
| A   | .190     | .205 | 4.83        | 5.21  |
| A1  | .090     | .100 | 2.29        | 2.54  |
| A2  | .075     | .085 | 1.91        | 2.16  |
| b   | .045     | .055 | 1.14        | 1.40  |
| b1  | .075     | .084 | 1.91        | 2.13  |
| b2  | .115     | .123 | 2.92        | 3.12  |
| C   | .024     | .031 | 0.61        | 0.80  |
| D   | .819     | .840 | 20.80       | 21.34 |
| E   | .620     | .635 | 15.75       | 16.13 |
| e   | .215 BSC |      | 5.45 BSC    |       |
| L   | .780     | .800 | 19.81       | 20.32 |
| L1  | .150     | .170 | 3.81        | 4.32  |
| Q   | .220     | .244 | 5.59        | 6.20  |
| R   | .170     | .190 | 4.32        | 4.83  |
| S   | .520     | .540 | 13.21       | 13.72 |
| T   | .620     | .640 | 15.75       | 16.26 |
| U   | .065     | .080 | 1.65        | 2.03  |

- 1 - GATE  
2 - DRAIN (COLLECTOR)  
3 - SOURCE (EMITTER)  
4 - NO CONNECTION

NOTE: This drawing will meet all dimensions requirement of JEDEC outline TO-247AD except screw hole.

| Symbol     | Test Conditions                                                                                                                  | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |               |
|------------|----------------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------|------|---------------|
|            |                                                                                                                                  | min.                                                                              | typ. | max.          |
| $V_F$      | $I_F = 60\text{ A}$ , $V_{GE} = 0\text{ V}$ ,<br>Note 1<br>$T_J = 150^\circ\text{C}$                                             |                                                                                   |      | 2.0 V<br>1.39 |
| $I_{RM}$   | $I_F = 60\text{ A}$ , $V_{GE} = 0\text{ V}$ , $-di_F/dt = 100\text{ A}/\mu$<br>$V_R = 100\text{ V}$<br>$T_J = 100^\circ\text{C}$ |                                                                                   |      | 8.3 A         |
| $t_{rr}$   | $I_F = 1\text{ A}$ ; $-di_F/dt = 200\text{ A}/\text{ms}$ ; $V_R = 30\text{ V}$                                                   |                                                                                   | 35   | ns            |
| $R_{thJC}$ |                                                                                                                                  |                                                                                   |      | 0.85 K/W      |

Notes 1: Pulse test,  $t \leq 300\ \mu\text{s}$ , duty cycle  $\leq 2\%$

- 2:  $R_{thJ-DCB}$  is the thermal resistance junction-to-internal side of DCB substrate.  
3:  $R_{thJC}$  is the thermal resistance junction-to-external side of DCB substrate.

IXYS reserves the right to change limits, test conditions, and dimensions.

|                                                                                  |           |           |           |           |           |           |             |             |             |           |
|----------------------------------------------------------------------------------|-----------|-----------|-----------|-----------|-----------|-----------|-------------|-------------|-------------|-----------|
| IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: | 4,850,072 | 4,931,844 | 5,034,796 | 5,063,307 | 5,237,481 | 5,381,025 | 6,404,065B1 | 6,162,665   | 6,534,343   | 6,583,505 |
|                                                                                  | 4,835,592 | 4,881,106 | 5,017,508 | 5,049,961 | 5,187,117 | 5,486,715 | 6,306,728B1 | 6,259,123B1 | 6,306,728B1 | 6,683,344 |

**Fig. 1. Output Characteristics  
@ 25 Deg. C**

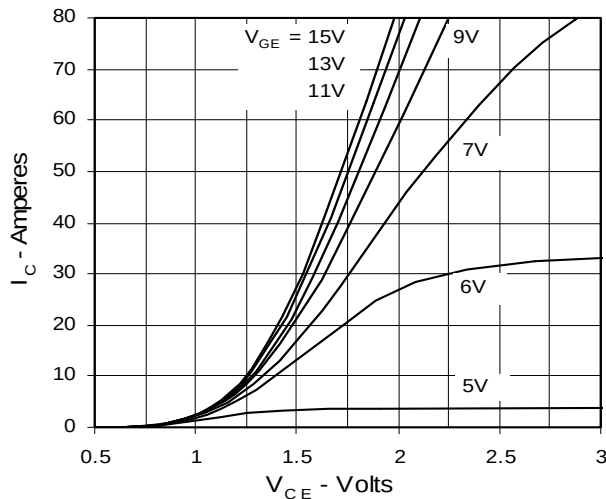


**Fig. 2. Extended Output Characteristics  
@ 25 deg. C**

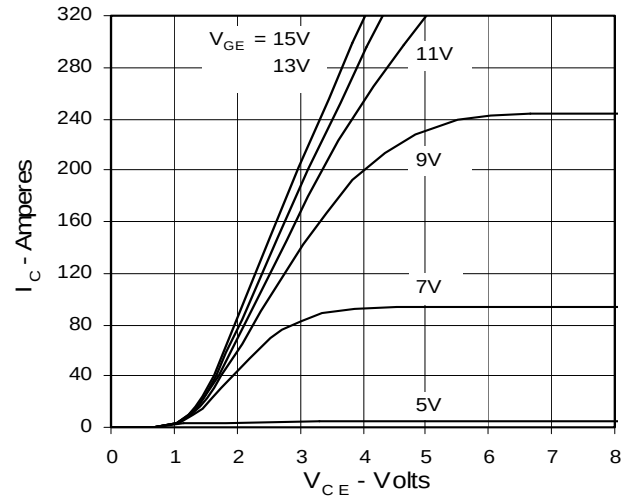


**Fig. 3. Output Characteristics  
@ 125 Deg. C**

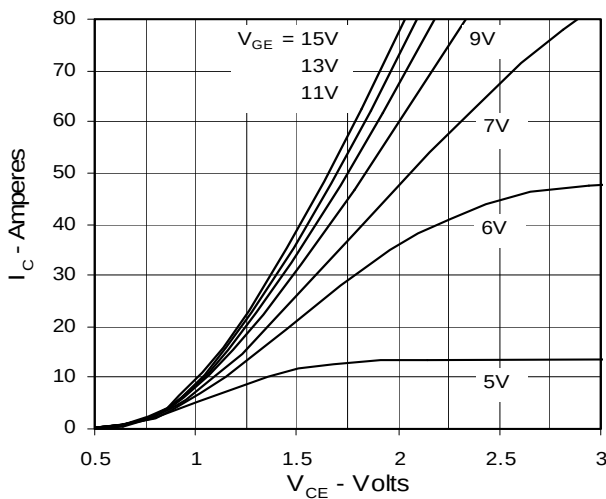


**Fig. 4. Dependence of  $V_{CE(sat)}$  on  
Temperature**

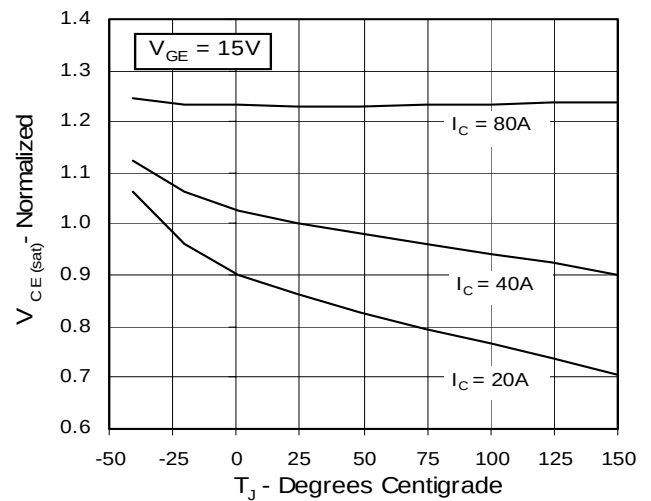


**Fig. 5. Collector-to-Emitter Voltage  
vs. Gate-to-Emitter voltage**

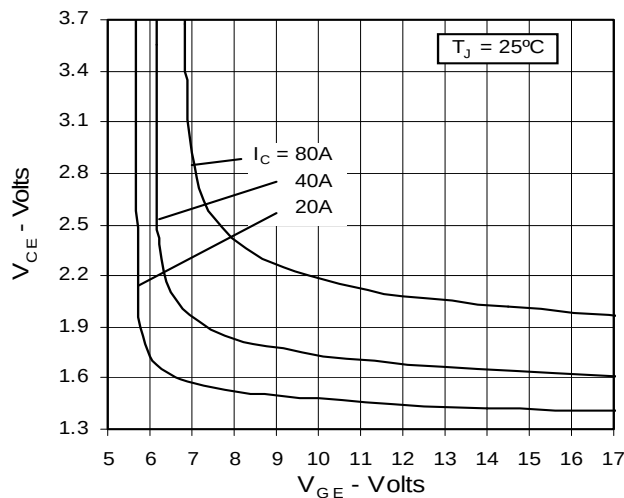


**Fig. 6. Input Admittance**

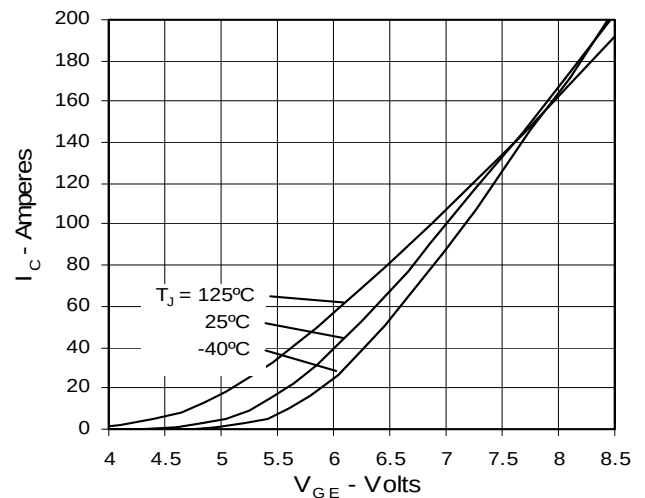


Fig. 7. Transconductance

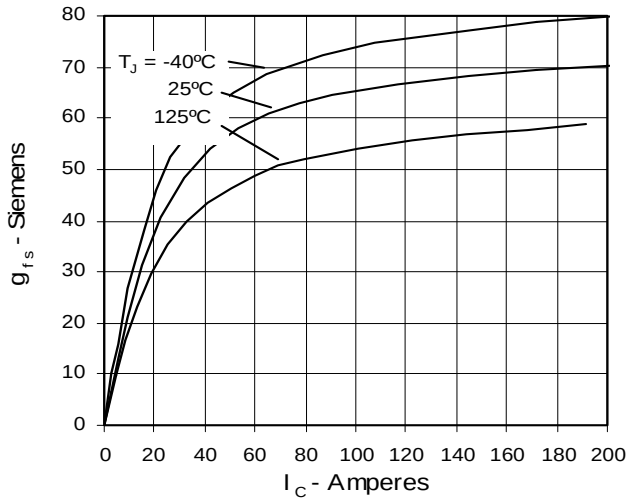


Fig. 8. Dependence of Turn-Off Energy on  $R_G$

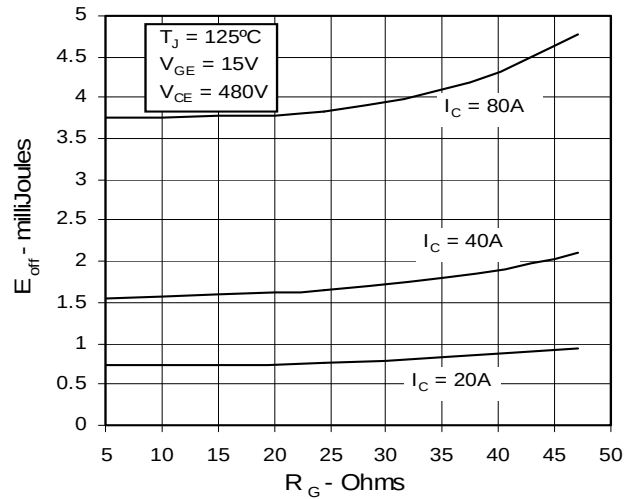


Fig. 9. Dependence of Turn-Off Energy on  $I_C$

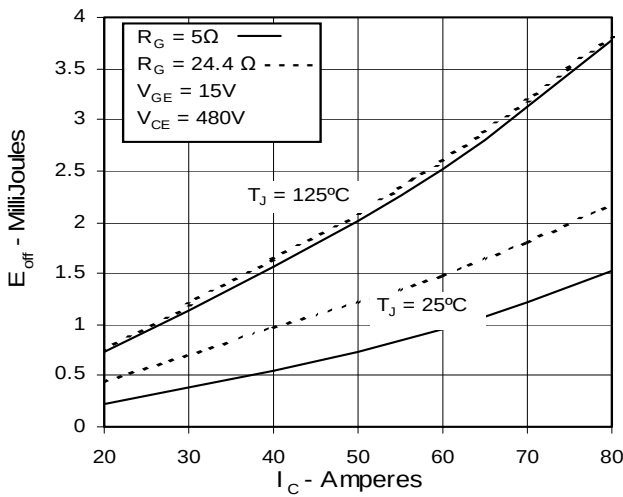


Fig. 10. Dependence of Turn-Off Energy on Temperature

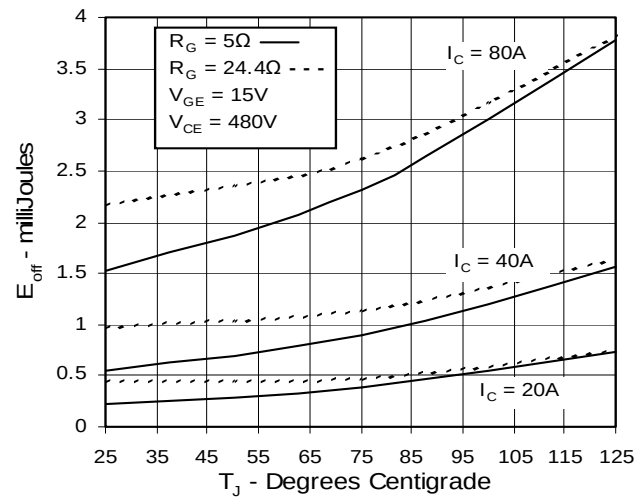


Fig. 11. Dependence of Turn-Off Switching Time on  $R_G$

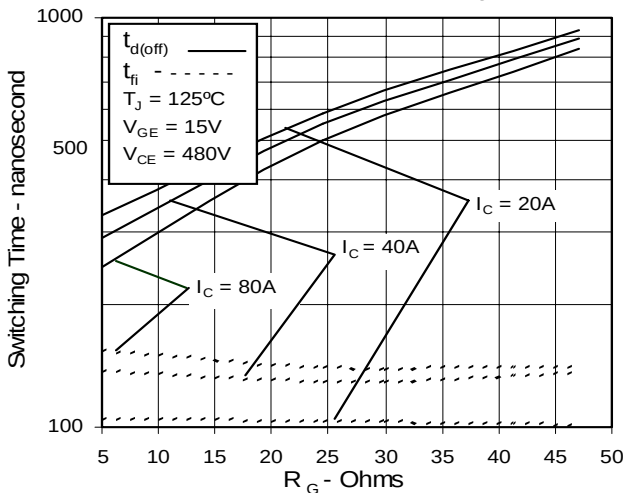
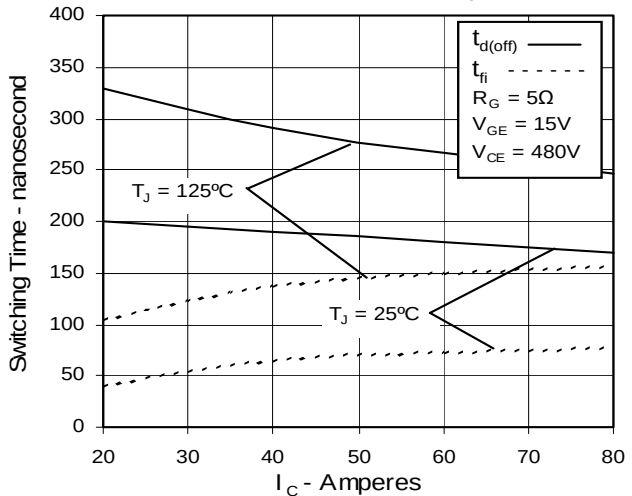


Fig. 12. Dependence of Turn-Off Switching Time on  $I_C$



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|           |           |           |           |           |           |             |             |             |           |
|-----------|-----------|-----------|-----------|-----------|-----------|-------------|-------------|-------------|-----------|
| 4,850,072 | 4,931,844 | 5,034,796 | 5,063,307 | 5,237,481 | 5,381,025 | 6,404,065B1 | 6,162,665   | 6,534,343   | 6,583,505 |
| 4,835,592 | 4,881,106 | 5,017,508 | 5,049,961 | 5,187,117 | 5,486,715 | 6,306,728B1 | 6,259,123B1 | 6,306,728B1 | 6,683,344 |

**Fig. 13. Dependence of Turn-Off Switching Time on Temperature**

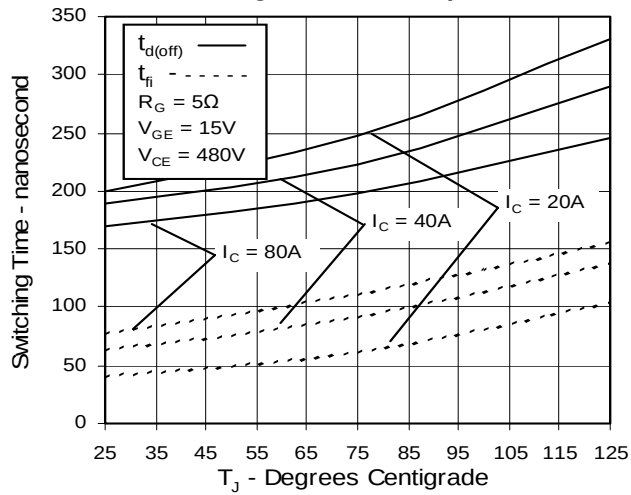


**Fig. 14. Reverse-Bias Safe Operating Area**

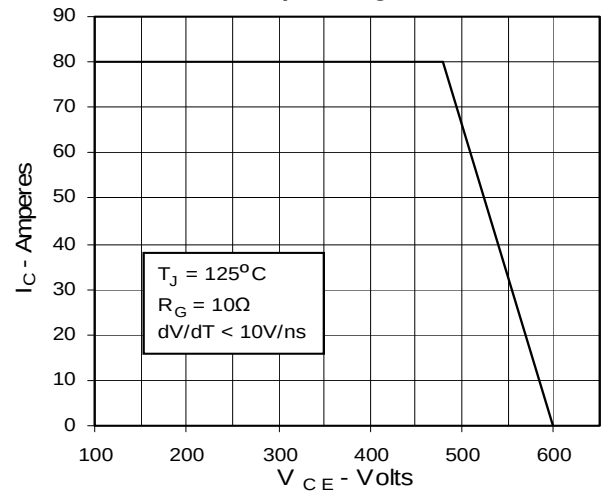


**Fig. 15. Gate Charge**

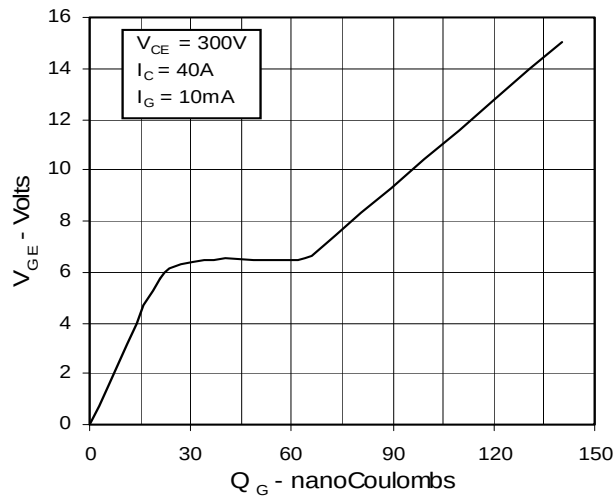


**Fig. 16. Capacitance**

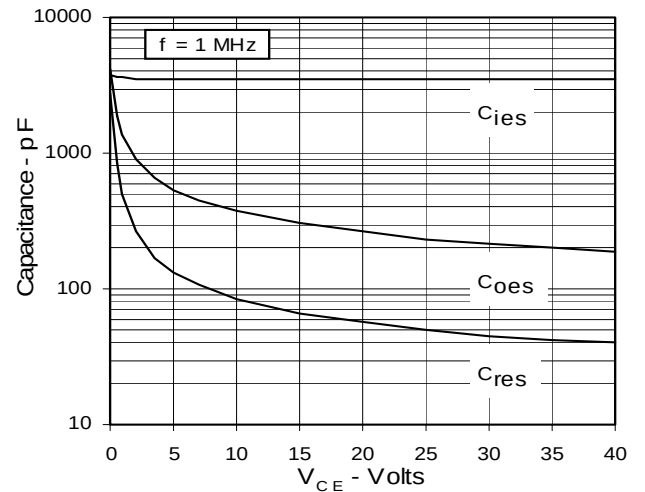
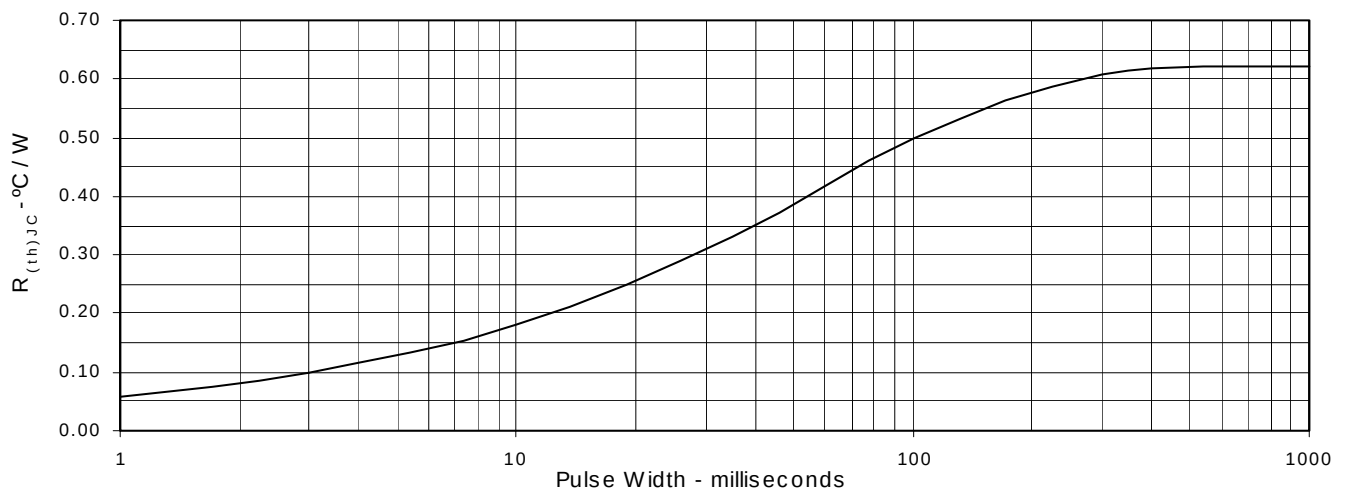


**Fig. 17. Maximum Transient Thermal Resistance**



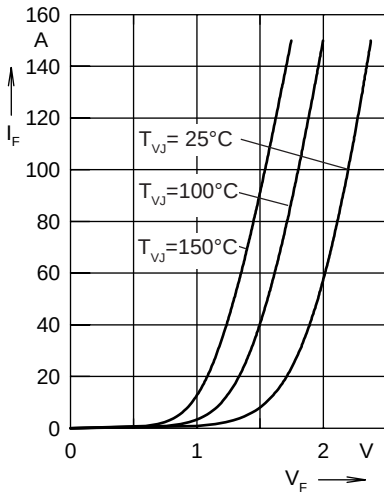


Fig. 18 Forward current  $I_F$  versus  $V_F$

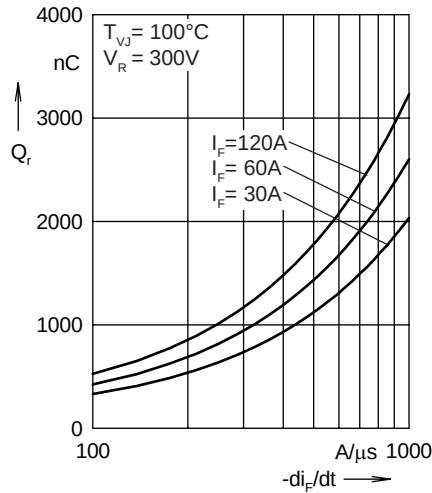


Fig. 19 Reverse recovery charge  $Q_r$  versus  $-di_F/dt$

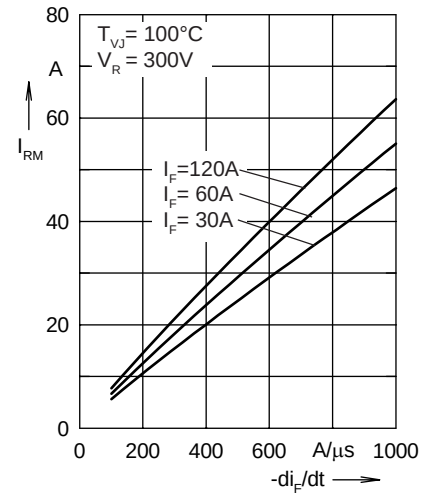


Fig. 20 Peak reverse current  $I_{RM}$  versus  $-di_F/dt$

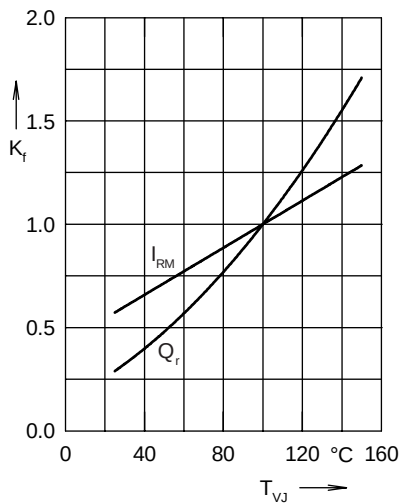


Fig. 21 Dynamic parameters  $Q_r$ ,  $I_{RM}$  versus  $T_{VJ}$

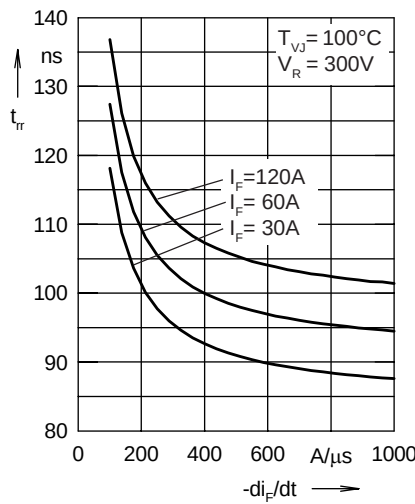


Fig. 22 Recovery time  $t_{rr}$  versus  $-di_F/dt$

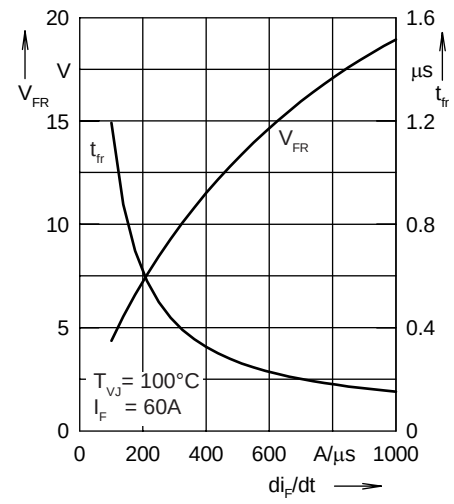


Fig. 23 Peak forward voltage  $V_{FR}$  and  $t_{fr}$  versus  $di_F/dt$

Constants for  $Z_{thJC}$  calculation:

| i | $R_{thi}$ (K/W) | $t_i$ (s) |
|---|-----------------|-----------|
| 1 | 0.3073          | 0.0055    |
| 2 | 0.3533          | 0.0092    |
| 3 | 0.0887          | 0.0007    |
| 4 | 0.1008          | 0.0399    |

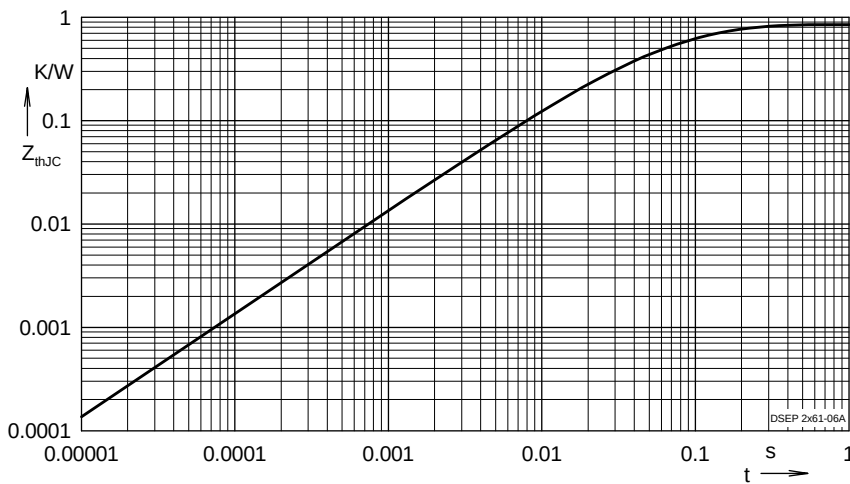


Fig. 24 Transient thermal resistance junction to case

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| 4,835,592 | 4,881,106 | 5,017,508 | 5,049,961 | 5,187,117 | 5,486,715 | 6,306,728B1 | 6,259,123B1 | 6,306,728B1 | 6,683,344 |